

TOSHIBA Field-Effect Transistor Silicon N / P Channel MOS Type

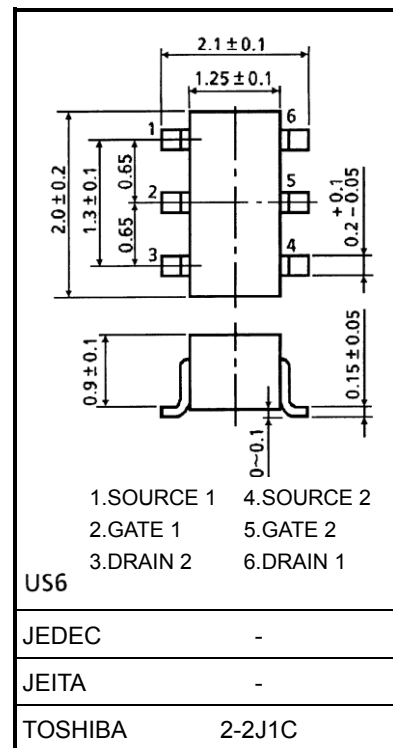
SSM6L35FU

○ High-Speed Switching Applications

○ Analog Switch Applications

- N-ch: 1.2-V drive
P-ch: 1.2-V drive
- N-ch, P-ch, 2-in-1
- Low ON-resistance
 - Q1 N-ch: $R_{ON} = 20 \Omega$ (max) (@ $V_{GS} = 1.2 \text{ V}$)
 $R_{ON} = 8 \Omega$ (max) (@ $V_{GS} = 1.5 \text{ V}$)
 $R_{ON} = 4 \Omega$ (max) (@ $V_{GS} = 2.5 \text{ V}$)
 $R_{ON} = 3 \Omega$ (max) (@ $V_{GS} = 4.0 \text{ V}$)
 - Q2 P-ch: $R_{ON} = 44 \Omega$ (max) (@ $V_{GS} = -1.2 \text{ V}$)
 $R_{ON} = 22 \Omega$ (max) (@ $V_{GS} = -1.5 \text{ V}$)
 $R_{ON} = 11 \Omega$ (max) (@ $V_{GS} = -2.5 \text{ V}$)
 $R_{ON} = 8 \Omega$ (max) (@ $V_{GS} = -4.0 \text{ V}$)

Unit: mm



US6

JEDEC

JEITA

TOSHIBA

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2-2J1C

Weight: 6.8 mg (typ.)

Q1 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	20	V
Gate-source voltage		V_{GSS}	±10	V
Drain current	DC	I_D	180	mA
	Pulse	I_{DP}	360	

Q2 Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	-20	V
Gate-source voltage		V_{GSS}	±10	V
Drain current	DC	I_D	-100	mA
	Pulse	I_{DP}	-200	

Absolute Maximum Ratings (Ta = 25 °C) (Common to the Q1, Q2)

Characteristics	Symbol	Rating	Unit
Drain power dissipation	P_D (Note 1)	200	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55 to 150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

Start of commercial production
2008-03

Q1 Electrical Characteristics (Ta = 25°C)

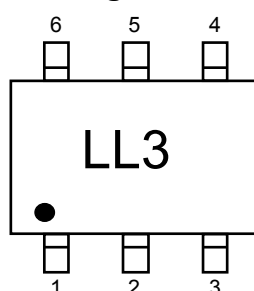
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 0.1\text{ mA}$, $V_{GS} = 0\text{ V}$	20	—	—	V
Drain cutoff current	I_{DSS}	$V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	1	μA
Gate threshold voltage	V_{th}	$V_{DS} = 3\text{ V}$, $I_D = 1\text{ mA}$	0.4	—	1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 3\text{ V}$, $I_D = 50\text{ mA}$ (Note 2)	115	—	—	mS
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = 50\text{ mA}$, $V_{GS} = 4\text{ V}$ (Note 2)	—	1.5	3	Ω
		$I_D = 50\text{ mA}$, $V_{GS} = 2.5\text{ V}$ (Note 2)	—	2	4	
		$I_D = 5\text{ mA}$, $V_{GS} = 1.5\text{ V}$ (Note 2)	—	3	8	
		$I_D = 5\text{ mA}$, $V_{GS} = 1.2\text{ V}$ (Note 2)	—	5	20	
Input capacitance	C_{iss}	$V_{DS} = 3\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	9.5	—	pF
Reverse transfer capacitance	C_{rss}		—	4.1	—	
Output capacitance	C_{oss}		—	9.5	—	
Switching time	Turn-on time	$V_{DD} = 3\text{ V}$, $I_D = 50\text{ mA}$, $V_{GS} = 0\text{ to }2.5\text{ V}$	—	115	—	ns
	Turn-off time		—	300	—	
Drain-source forward voltage	V_{DSF}	$I_D = -180\text{ mA}$, $V_{GS} = 0\text{ V}$ (Note 2)	—	-0.9	-1.2	V

Q2 Electrical Characteristics (Ta = 25°C)

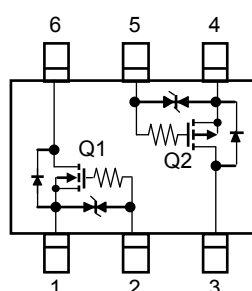
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 10\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 10	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -0.1\text{ mA}$, $V_{GS} = 0\text{ V}$	-20	—	—	V
Drain cutoff current	I_{DSS}	$V_{DS} = -20\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	-1	μA
Gate threshold voltage	V_{th}	$V_{DS} = -3\text{ V}$, $I_D = -1\text{ mA}$	-0.4	—	-1.0	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3\text{ V}$, $I_D = -50\text{ mA}$ (Note 2)	77	—	—	mS
Drain-source ON-resistance	$R_{DS(ON)}$	$I_D = -50\text{ mA}$, $V_{GS} = -4\text{ V}$ (Note 2)	—	4.3	8	Ω
		$I_D = -50\text{ mA}$, $V_{GS} = -2.5\text{ V}$ (Note 2)	—	5.6	11	
		$I_D = -5\text{ mA}$, $V_{GS} = -1.5\text{ V}$ (Note 2)	—	8.2	22	
		$I_D = -2\text{ mA}$, $V_{GS} = -1.2\text{ V}$ (Note 2)	—	11	44	
Input capacitance	C_{iss}	$V_{DS} = -3\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	12.2	—	pF
Reverse transfer capacitance	C_{rss}		—	6.5	—	
Output capacitance	C_{oss}		—	10.4	—	
Switching time	Turn-on time	$V_{DD} = -3\text{ V}$, $I_D = -50\text{ mA}$, $V_{GS} = 0\text{ to }-2.5\text{ V}$	—	175	—	ns
	Turn-off time		—	251	—	
Drain-source forward voltage	V_{DSF}	$I_D = 100\text{ mA}$, $V_{GS} = 0\text{ V}$ (Note 2)	—	0.83	1.2	V

Note 2: Pulse test

Marking

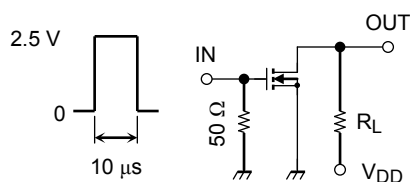


Equivalent Circuit (top view)



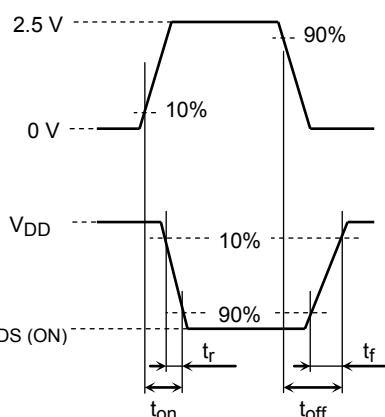
Q1 Switching Time Test Circuit

(a) Test Circuit

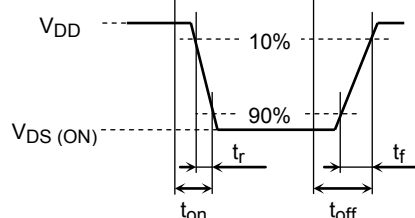


$V_{DD} = 3 \text{ V}$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 $(Z_{out} = 50 \Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}

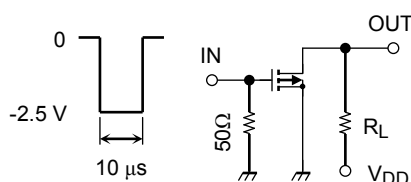


(c) V_{OUT}



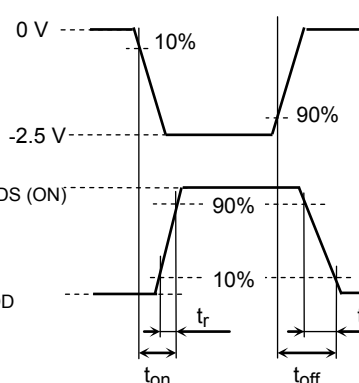
Q2 Switching Time Test Circuit

(a) Test Circuit

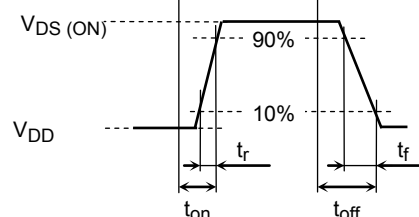


$V_{DD} = -3 \text{ V}$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 $(Z_{out} = 50 \Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}



(c) V_{OUT}



Q1 Usage Considerations

Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (1 mA for the Q1 of the SSM6L35FU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

Q2 Usage Considerations

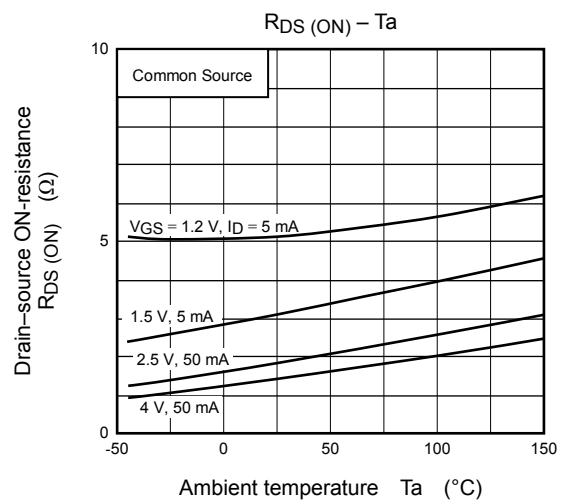
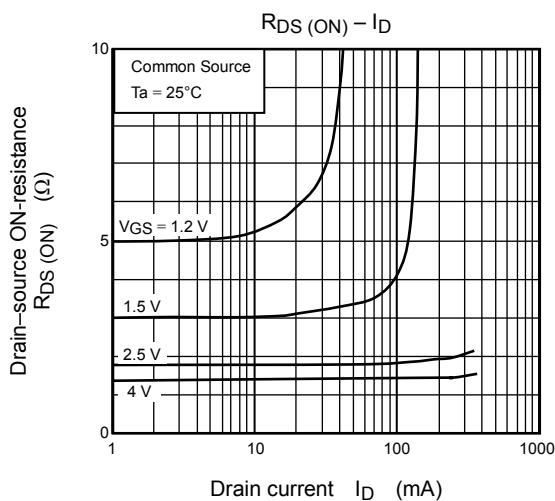
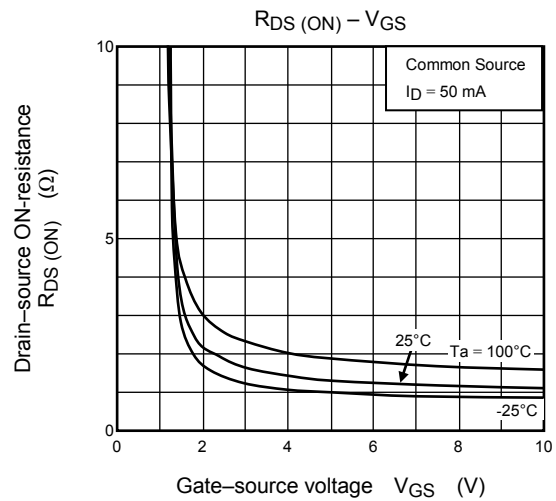
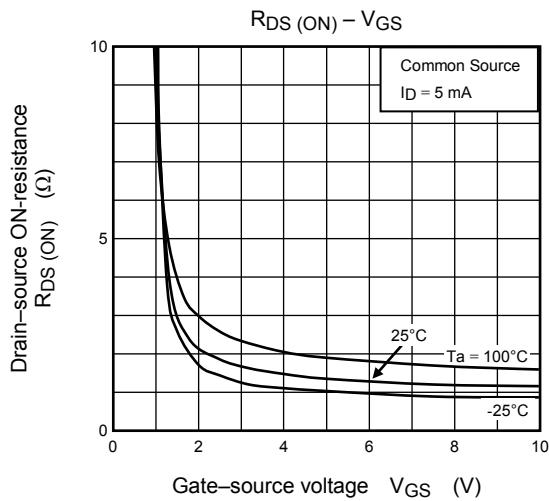
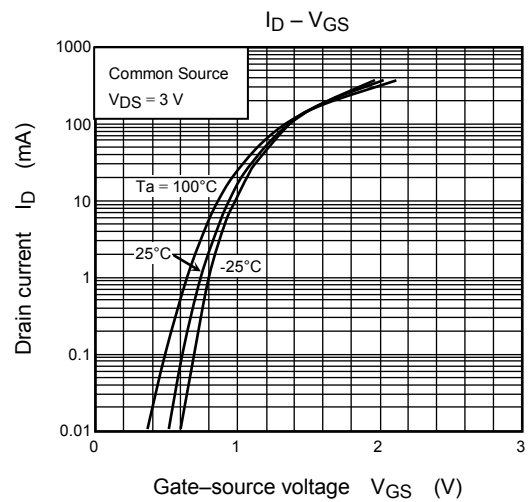
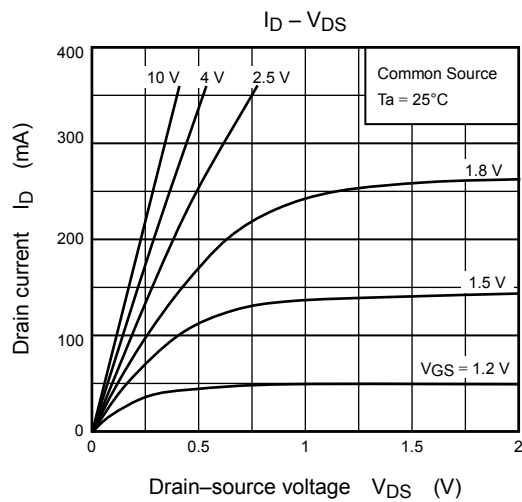
Let V_{th} be the voltage applied between gate and source that causes the drain current (I_D) to below (-1 mA for the Q2 of the SSM6L35FU). Then, for normal switching operation, $V_{GS(on)}$ must be higher than V_{th} , and $V_{GS(off)}$ must be lower than V_{th} . This relationship can be expressed as: $V_{GS(off)} < V_{th} < V_{GS(on)}$.

Take this into consideration when using the device.

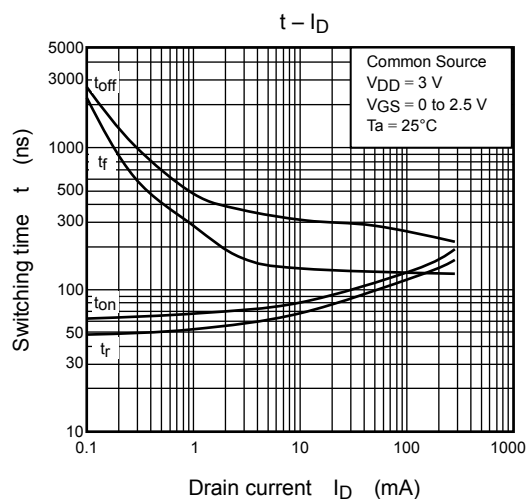
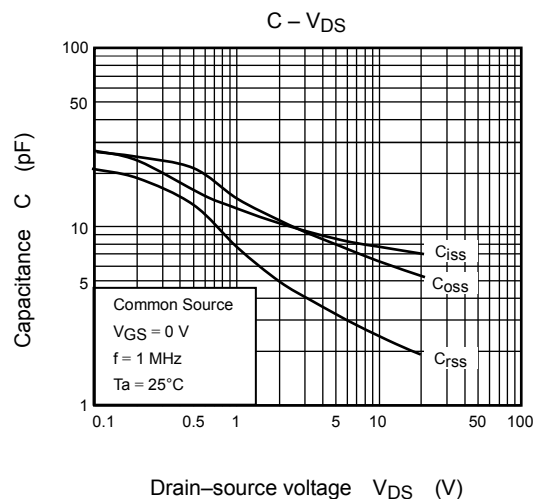
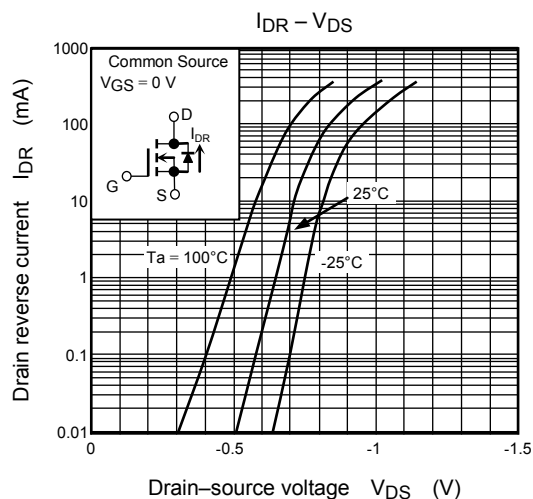
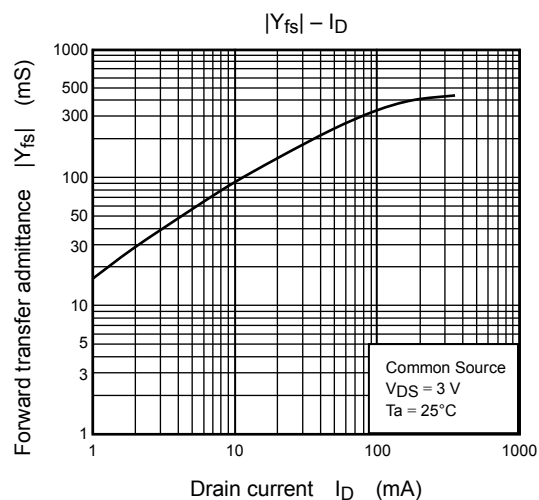
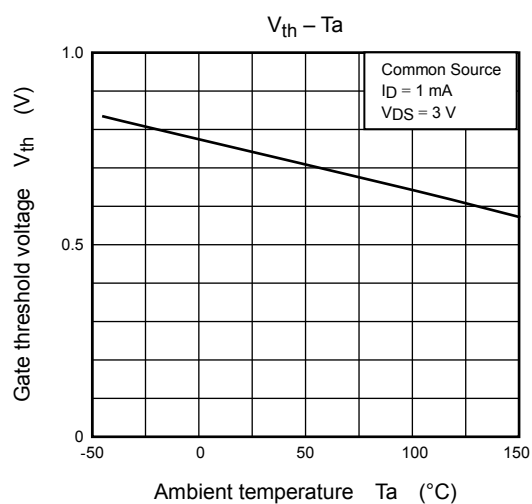
Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

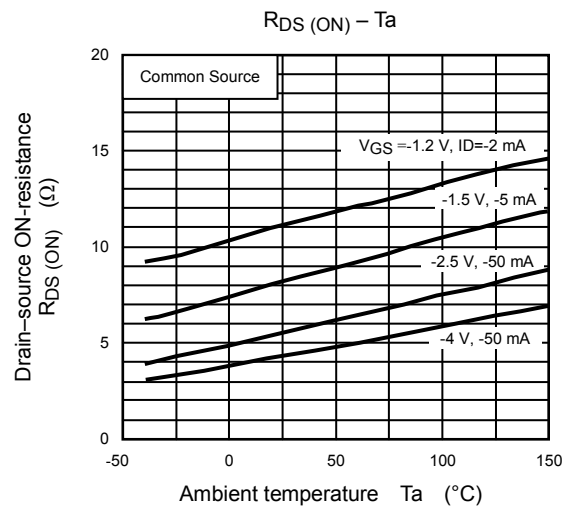
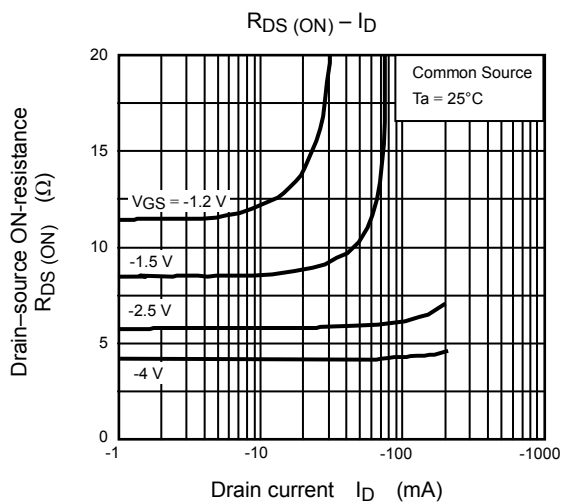
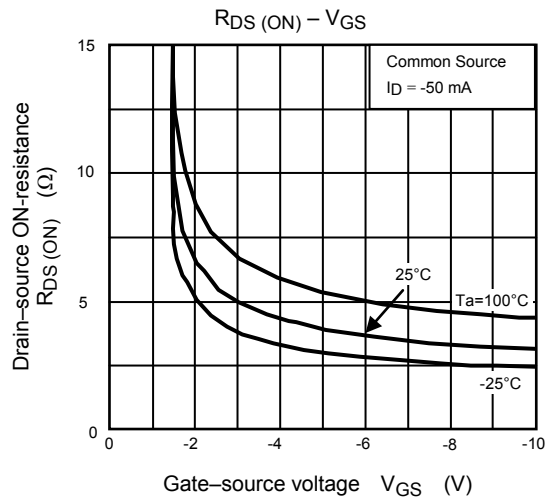
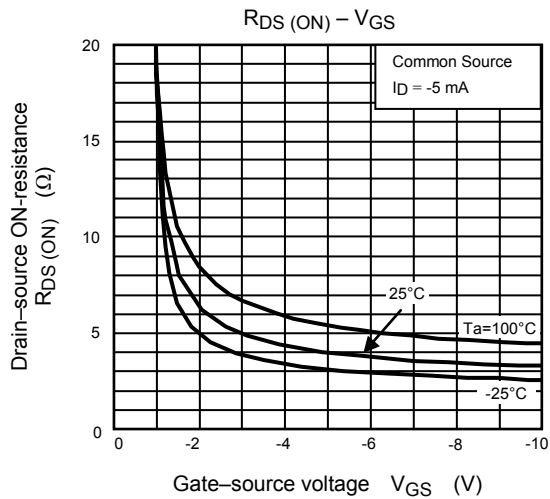
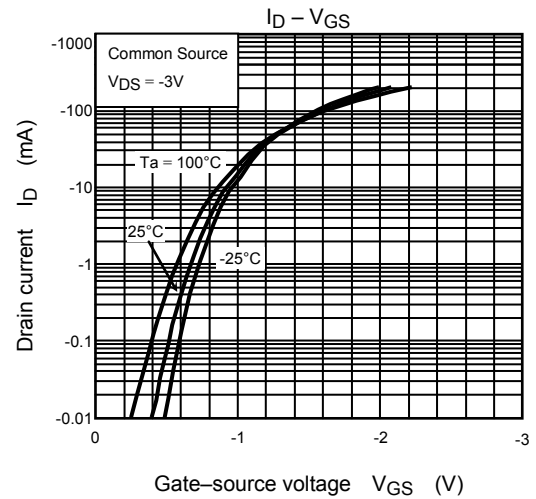
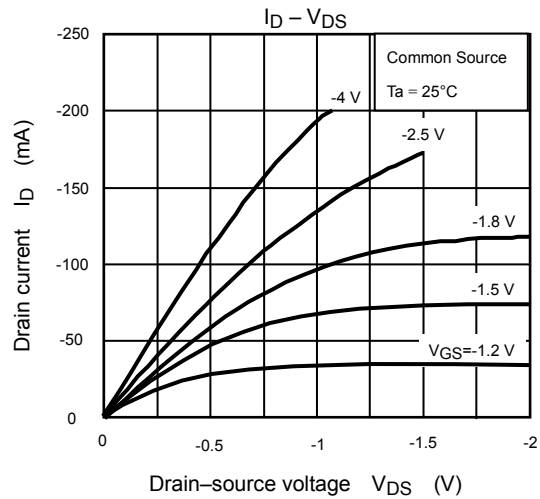
Q1 (N-ch MOSFET)



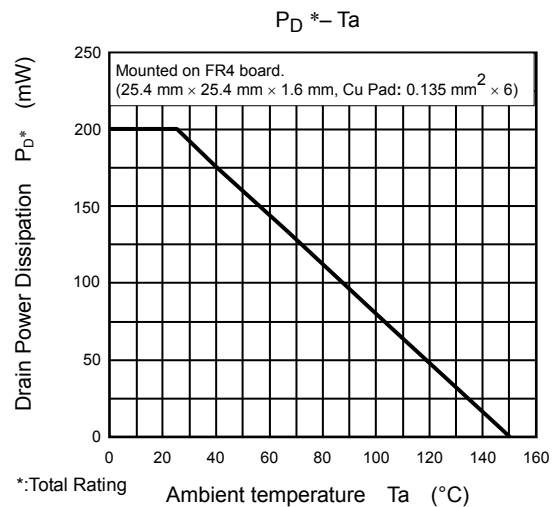
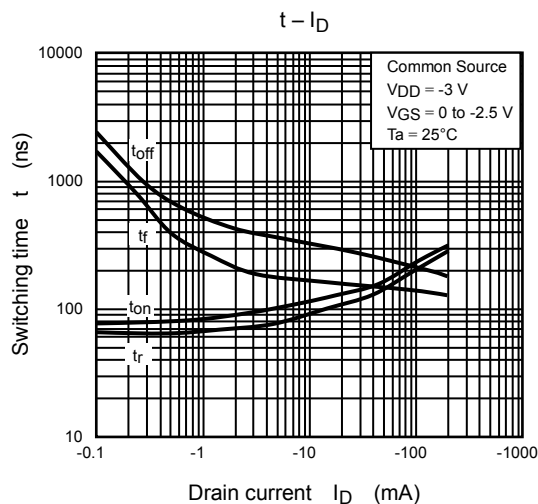
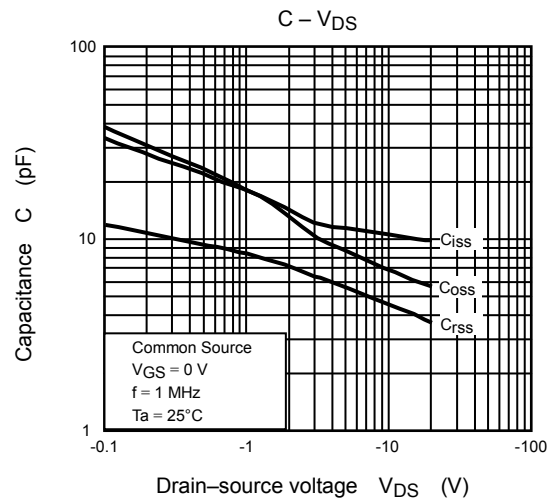
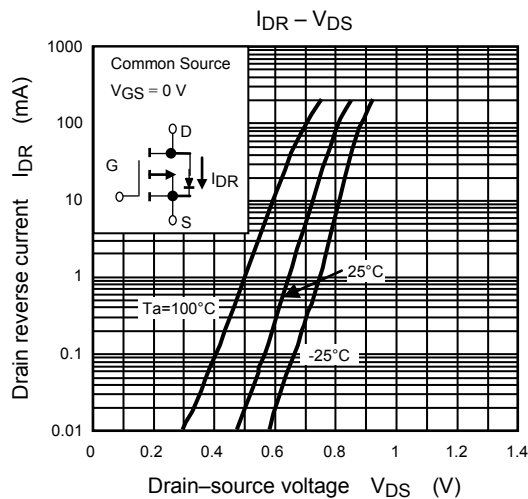
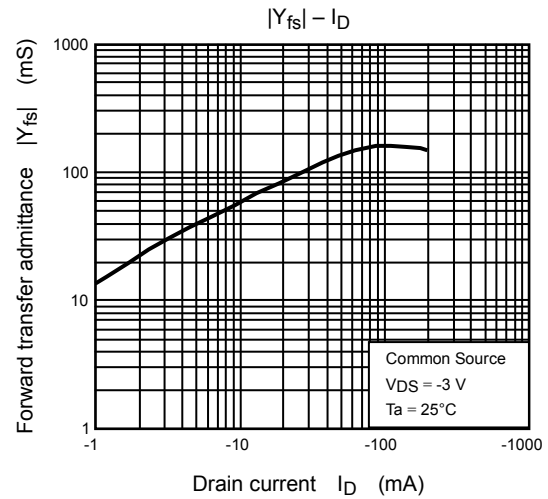
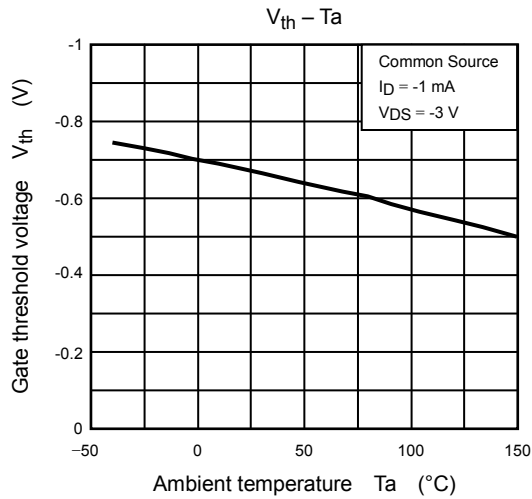
Q1 (N-ch MOSFET)



Q2 (P-ch MOSFET)



Q2 (P-ch MOSFET)



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